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# Tailoring the defects of sub-100 nm multipodal titanium nitride/oxynitride nanotubes for efficient water splitting performance†

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Deciphering the photocatalytic-defect relationship of photoanodes can pave the way towards the rational design for high-performance solar energy conversion. Herein, we rationally designed uniform and aligned ultrathin sub-100 nm multipodal titanium nitride/oxynitride nanotubes (TiON<sub>x</sub>NTs) ( $x = 2, 4, \text{ and } 6$  h) via the anodic oxidation of Ti-foil in a formamide-based electrolyte followed by annealing under ammonia gas for different durations. XPS, XPS imaging, Auger electron spectra, and positron annihilation spectroscopy disclosed that the high nitridation rate induced the generation of a mixture of Ti-nitride and oxynitride with various vacancy-type defects, including monovacancies, vacancy clusters, and a few voids inside TiO<sub>x</sub>NTs. These defects decreased the bandgap energy to 2.4 eV, increased visible-light response, and enhanced the incident photon-to-current collection efficiency (IPCE) and the photocurrent density of TiON<sub>x</sub>NTs by nearly 8 times compared with TiO<sub>2</sub>NTs, besides a quick carrier diffusion at the nanotube/electrolyte interface. The water-splitting performance of sub-100 nm TiON<sub>6</sub>NT multipodal nanotubes was superior to the long compacted TiON<sub>x</sub>NTs with different lengths and TiO<sub>2</sub> nanoparticles. Thus, the optimization of the nitridation rate tailors the defect concentration, thereby achieving the highest solar conversion efficiency.

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## Introduction

Biofuel,<sup>1,2</sup> gas conversion reactions,<sup>3–7</sup> anodic and cathodic reactions (*i.e.*, water splitting,<sup>8,9</sup> methanol<sup>10</sup>/ethanol oxidation,<sup>1</sup> and oxygen reduction<sup>11,12</sup>) driven by porous catalysts are highly promising green and sustainable energy sources. Porous titanium nanostructures, especially nanotubes, have grabbed appreciable attention in photocatalytic water oxidation, owing to their excellent activity, high surface area, low-density, and abundant active sites.<sup>13,14</sup> However, the wide bandgap and lower visible light-harvesting characteristics are critical, thus making TiO<sub>2</sub> impractical for solar-driven energy conversion devices.<sup>15,16</sup> As such, various efforts have been devoted to defeating such barriers, which are based on reducing the bandgap and delaying the recombination of the photogenerated electrons and holes.<sup>17–19</sup> This can be achieved throughout the creation of various defects inside the lattice structure of TiO<sub>2</sub> via its doping with non-metal dopants such as H<sub>2</sub>, N, S, Cu, and F.<sup>20–22</sup> These vacancy-type defects act as electron scavengers that retard the

electron-hole pair recombination and enhance the number of charge carriers without diminishing the crystallinity and/or photocurrent density of TiO<sub>2</sub>.<sup>23,24</sup> This is in addition to significantly decreasing the bandgap energy of TiO<sub>2</sub>, as well as enhancing the UV-visible light responses. To this end, N-doped porous TiO<sub>2</sub>, in the form of titanium oxynitride (TiON), is of great importance in solar-driven water splitting, owing to the excellent visible-light absorption and suitable bandgap.<sup>25–28</sup> For example, mesoporous TiON films formed through combining sol-gel chemistry, evaporation-induced self-assembly, flash crystallization, and ammonia treatment displayed superior photocatalytic activity as compared to TiO<sub>2</sub> for the degradation of methylene blue and lauric acid.<sup>29</sup> Unlike other porous morphologies, nanotubes have higher surface areas, more active sites, quick charge collection efficiencies, greater UV-visible light responses, and enhanced mass transfer. Also, nanotubes provide various active sites that enhance the adsorption of reactants and the desorption of products.<sup>30,31</sup> However, the fabrication of porous TiON nanotubes has rarely been reported, and they are not sufficiently emphasized for water-splitting as compared with other nanostructures. For instance, TiON-NTs prepared by the annealing of TiO<sub>2</sub>NTs under ammonia exhibited a significant enhancement in the photocurrent density and UV-visible light responses of TiO<sub>2</sub>NTs.<sup>32</sup>

Likewise, TiON-NTs obtained using the anodization of TiN alloy enhanced the incident photon-to-current collection

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efficiency (IPCE) and visible-light responses substantially as compared to  $\text{TiO}_2$ .<sup>33</sup> Despite the significant advances in the fabrication of  $\text{TiON}$ -NTs, their photocatalytic-defect relationship was not emphasized and is still unknown. Most of the previous reports focused only on the hydrogenated and/or oxygenated  $\text{TiO}_2$  nanocrystals to induce the formation of oxygen vacancies and defects inside the  $\text{TiO}_2$  nanostructures.<sup>34–38</sup> Some studies reported that the photocatalytic efficiency of  $\text{TiO}_2$  nanocrystals could be enhanced as the concentration of bulk defects to surface defects decreased due to the improved isolation efficiency of the photogenerated electrons–holes.<sup>37,39,40</sup> The defects can generate trapping centers that accelerate the electron–hole combination besides deteriorating the crystallinity and/or photocurrents of  $\text{TiO}_2$ .<sup>37,39,41</sup> Thus, the photocatalytic-defect relationship of  $\text{TiO}_2$  is hitherto unravelled and ambiguous. Consequently, defect engineering in  $\text{TiON}$ -NTs and deciphering the defects-photocatalytic relationship can boost their charge carrier collection efficiency while preserving the crystallinity.<sup>42</sup> This can also pave the way towards integrating  $\text{TiON}$ -NTs into cost-effective and efficient, practical solar-driven water-splitting devices.

Herein ultrathin sub-100 nm multipodal  $\text{TiON}_x$ -NTs nanotubes were fabricated using anodic oxidation followed by annealing under ammonia. The nitridation rate was optimized to tailor the concentration and types of the vacancy-type defects inside  $\text{TiO}_2$ -NTs. The nature and concentration of the vacancy-type defects were confirmed using various characterization techniques like transmission electron microscopy (TEM), X-ray photoelectron spectroscopy (XPS), X-ray diffraction (XRD), and positron annihilation spectroscopy (PALS). In addition, the photoelectrochemical water splitting performance of the ammonia-annealed  $\text{TiON}_x$ -NTs samples was benchmarked relative to the air-annealed  $\text{TiO}_2$ -NTs to elucidate the relationship between the photocatalytic performance of the ammonia-annealed  $\text{TiON}_x$ -NTs and air-annealed  $\text{TiO}_2$ -NTs. Unlike previous reports, our newly designed  $\text{TiON}_x$ -NTs possess various inimitable structure and composition merits, including a porous one-dimensional ultrashort sub-100 nm multipodal nanotube structure that provides a short electron pathway and maximizes the charge collection efficiency. The N-doping in  $\text{TiO}_2$ -NTs forms a mixture of Ti-nitride and oxynitride with various defects such as monovacancies, vacancy clusters, and a few voids that can reduce the valence band edge and enhance the visible light response of  $\text{TiON}_x$ -NTs. Furthermore, our obtained materials were formed as solid nanosheets ornamented with nanotubes that could be directly used as anodes without additional steps for the activation and/or conversion into working electrodes, which are highly essential features for practical applications.

## Experimental

### Chemicals and materials

Polyvinylpyrrolidone (PVP, 40 000), titanium foil (0.25 mm thick, purity 99.8%), ammonium fluoride ( $\text{NH}_4\text{F}$ ), and formamide were purchased from Sigma-Aldrich Chemie GmbH (Munich, Germany).

### Synthesis of $\text{TiON}_x$ -NTs

A Pt sheet was used as the counter electrode during the anodization of Ti foil in an aqueous formamide solution containing 1.2% of  $\text{NH}_4\text{F}$ , 1.3 wt% PVP, and 3 mL  $\text{H}_2\text{O}$ .<sup>43</sup> The anodization process was carried out for 2.5 h in an ice bath at 0 °C under 36 V (0.1 V  $\text{s}^{-1}$ ). First, the current was maintained at 25–27 mA under acidic conditions using 0.1 M acetic acid.<sup>43</sup> Then, the as-anodized foils were rinsed thoroughly with distilled water and annealed at 450 °C (2 °C  $\text{min}^{-1}$ ) for 1.5 h under air to obtain  $\text{TiO}_2$ -NTs. Next, the resultant  $\text{TiO}_2$ -NTs were annealed under ammonia flow (200 sccm) at 600 °C for 2, 4, and 6 h to form  $\text{TiON}_2$ -NTs,  $\text{TiON}_4$ -NTs, and  $\text{TiON}_6$ -NTs, respectively. The heating and cooling rates were 1 °C  $\text{min}^{-1}$ .

### Material characterization

The morphology and composition of typically synthesized nanotubes were characterized by SEM (Hitachi S-4800, Hitachi, Tokyo, Japan) equipped with energy-dispersive X-ray spectroscopy (EDX) and TEM (TecnaiG220, FEI, Hillsboro, OR, USA). The XPS was measured on an Ultra DLD XPS Kratos, Manchester, UK spectrometer equipped with a monochromatic Al  $K\alpha$  radiation source (1486.6 eV) under a UHV environment (*ca.*  $5 \times 10^{-9}$  torr). The Auger electron spectra (AES) were measured on an Ultra DLD XPS spectrometer (Kratos, Manchester, UK) using a high-energy Ag  $L\alpha$  monochromatic X-ray source. The XRD patterns were obtained using an X'Pert-Pro MPD diffractometer (PANalytical Co., Netherlands) with a Cu  $K\alpha$  X-ray source ( $\lambda = 1.540598 \text{ \AA}$ ). The ultraviolet-visible (UV-Vis) diffuse reflectance spectra were obtained using a diffuse reflectance accessory of a UV-vis spectrophotometer (UV2550, Shimadzu, Japan). The positron annihilation lifetime spectroscopy (PALS) was recorded using a  $^{22}\text{Na}$  ( $\sim 10 \mu\text{Ci}$ ) radioactive positron source.

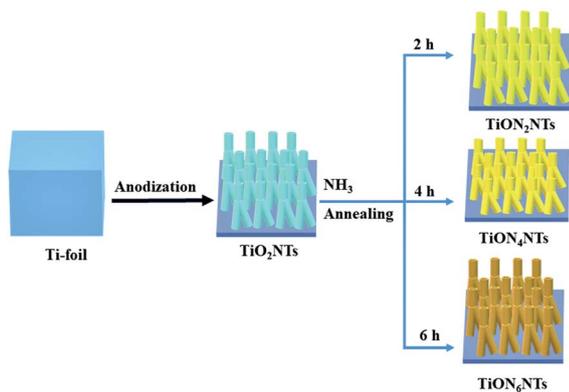
### Water-splitting reaction

The photoelectrochemical measurements were carried out on a Gamry electrochemical analyzer (reference 3000, Gamry Co., USA) using a conventional three-electrode photo-glass cell involving a platinum wire as the counter electrode, reversible hydrogen electrode (RHE) (reference electrode), and our prepared samples were used as working electrodes. The sunlight was simulated with a xenon ozone-free lamp (100 W) (Abet Technologies, USA) and AM 1.5G filter at 100  $\text{mW cm}^{-2}$ . All the measured currents were normalized to the geometric area of the working-electrodes, and all potentials were recorded after the *IR*-drop correction.

## Results and discussion

$\text{TiO}_2$ -NTs were initially synthesized *via* the electrochemical anodization of titanium foils in the formamide-based electrolyte and then were annealed under ammonia gas for different durations (Scheme 1).<sup>42,43</sup> The formamide, with its remarkable ability to control the electrolyte solution's viscosity and conductivity, prevents the current oscillation due to the “in-pore” local pH variation providing favorable conditions for tailoring the fabrication of ordered, aligned, and oriented thin-



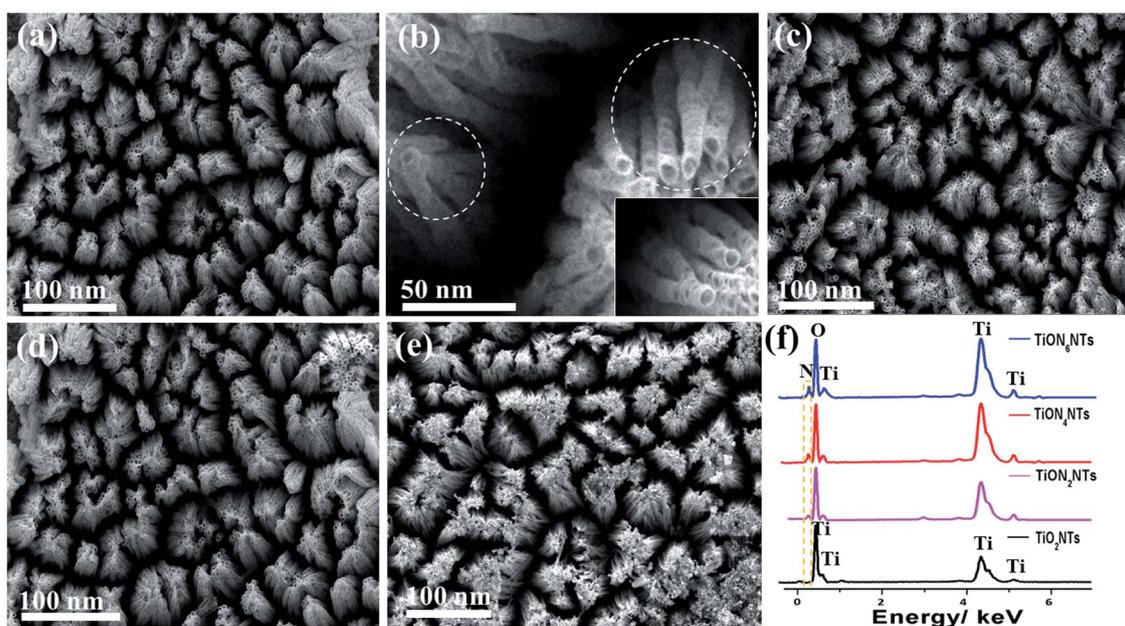


**Scheme 1** The formation process of  $\text{TiO}_2\text{NTs}$  and  $\text{TiON}_2\text{NTs}$ ,  $\text{TiON}_4\text{NTs}$ , and  $\text{TiON}_6\text{NTs}$ .

walled multipodal nanotubes. The solution pH was adjusted by adding 0.1 M acetic acid, and 1 wt% of PVP was used for structural stability.<sup>43</sup> The electrolyte solution should be mixed well under heating at 100 °C before the anodization process to ensure the mixing of the precursors and avoid the precipitation of  $\text{NH}_4\text{F}$ . Fig. 1a reveals the SEM image of the typically synthesized  $\text{TiO}_2\text{NTs}$ . The nanotube arrays were formed in well-ordered, homogeneous, and vertically aligned nanotubes without noticeable debris or distortion. The side view shows that the nanotubes are multipodal with two or more legs, as indicated by the dashed circles (Fig. 1b). The average nanotube length was about  $80 \pm 2$  nm, the pore diameter was  $12 \pm 1$  nm, and the wall thickness was 3–5 nm (Fig. 1b). The as-formed  $\text{TiO}_2\text{NTs}$  were annealed under ammonia gas for 2, 4, and 6 h

to form  $\text{TiON}_2\text{NTs}$ ,  $\text{TiON}_4\text{NTs}$ , and  $\text{TiON}_6\text{NTs}$ , respectively (Fig. 1c–e). Interestingly, the ammonia-annealed samples retained their porous nanotube structures without any alteration in the morphology and/or dimensions but with only a slight tight packing at a high nitridation rate (6 h). This confirmed the structural stability of the as-synthesized NTs.

The composition of the as-synthesized materials was investigated by the EDX analysis, which demonstrated the presence of Ti and O in  $\text{TiO}_2\text{NTs}$  with atomic content of 33.9 and 66.1%. The ammonia-annealed samples revealed Ti, O, and an additional N peak. The intensity of the N peak increased with increasing the nitridation time, as indicated by the dashed square (Fig. 1f). From EDX analysis, the estimated N-content in  $\text{TiON}_2\text{NTs}$ ,  $\text{TiON}_4\text{NTs}$ , and  $\text{TiON}_6\text{NTs}$  was determined to be 1.7, and 4.9%, respectively. The as-made NTs were immersed in hydrochloric acid to peel off the NTs from the sheets. Fig. 2a shows the TEM image of  $\text{TiO}_2\text{NTs}$ , which demonstrates the porous nanotube morphology. The high-resolution TEM (HR-TEM) image of  $\text{TiO}_2\text{NTs}$  showed the crystalline anatase phase structure. The interplanar distance ( $d$ -spacing) was determined to be 3.57 Å, assigned to the 101 facets of  $\text{TiO}_2$  anatase (Fig. 2b). The selected area electron diffraction (SAED) pattern disclosed the set of the typical rings attributed to the (011), (004), (020), (015), (024), (220), and (125) facets of anatase  $\text{TiO}_2$ , agreeing with previous reports.<sup>44</sup> After nitridation, the  $\text{TiON}_2\text{NTs}$ ,  $\text{TiON}_4\text{NTs}$ , and  $\text{TiON}_6\text{NTs}$ , preserved their porous nanotube morphology (Fig. 2c, e and g). The HRTEM images of ammonia-annealed samples showed their amorphous crystalline structure. Intriguingly, the determined  $d$ -spacings were about 0.354, 0.352, 0.350, and 0.346 nm in  $\text{TiO}_2\text{NTs}$ ,  $\text{TiON}_2\text{NTs}$ ,  $\text{TiON}_4\text{NTs}$ , and  $\text{TiON}_6\text{NTs}$ , respectively, assigned to the facets of anatase (Fig. 2d, f and h).<sup>25</sup> The slight



**Fig. 1** SEM image of the typically prepared (a and b)  $\text{TiO}_2\text{-NTs}$ , (c)  $\text{TiON}_2\text{NTs}$ , (d)  $\text{TiON}_4\text{NTs}$ , and (e)  $\text{TiON}_6\text{NTs}$ . (f) EDX of the typically synthesized materials.



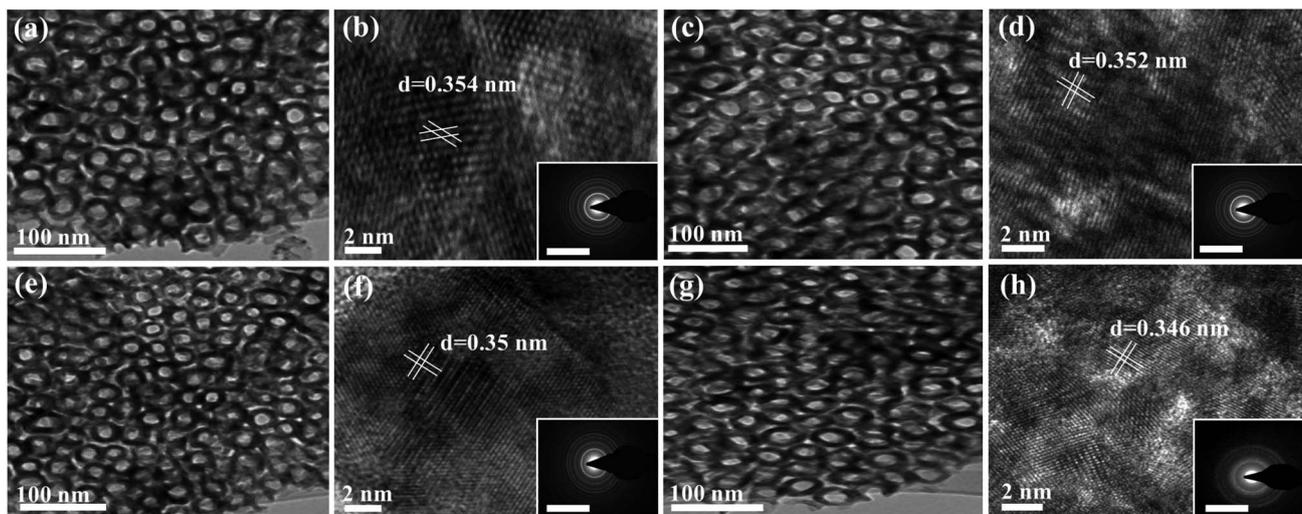


Fig. 2 (a, c, e and g) TEM images and (b, d, f and h) HRTEM images of  $\text{TiO}_2\text{NTs}$ ,  $\text{TiON}_2\text{NTs}$ ,  $\text{TiON}_4\text{NTs}$ , and  $\text{TiON}_6\text{NTs}$ , respectively, and their SAED patterns are shown as insets. The indicated scale bars in the insets of (b, d, f and h) are 5 nm.

decrease in the  $d$ -spacing of ammonia-annealed NTs relative to air-annealed NTs plausibly originated from the Ti-N and/or TiON legend effect, which compresses the lattice spacing of  $\text{TiO}_2$ . Notably, although the surface-disordered domain was boosted clearly at a high nitridation rate, there was no phase transformation in the lattice structure, suggesting their stability. Simultaneously, the SAED exhibited the typical rings associated with the (110), (111), (020), (015), (022), (220), and (113) facets of a mixture of anatase, TiN, and TiON phases (Fig. 2d, f and h).

The crystalline structures of the as-synthesized  $\text{TiON}_x\text{NTs}$  as compared to  $\text{TiO}_2\text{NTs}$  were investigated *via* XRD analysis (Fig. 3). The air-annealed  $\text{TiO}_2\text{NTs}$  showed the main characteristic diffraction peaks attributed to the tetragonal phase matched with (ICSD: 172914) along with some peaks of

tetragonal rutile (ICSD: 33838) (Fig. 3a). After the nitridation, there was a notable change in the XRD patterns in the formed  $\text{TiO}_x\text{NNTs}$ . In the  $\text{TiO}_x\text{NNTs}$  the diffraction patterns of  $\text{TiO}_2(011)$ , (020), and (220) were disappeared, whereas the (131) and (222) of TiN (ICSD: 426340) were observed, along with the enhancement in the intensity of (111), (020), (022), and (113) of TiN (ICSD: 236801) (Fig. 3a).

The TiN peaks overlapped with the  $\text{TiO}_2$  peaks, which is in line with other reports.<sup>33,42,45</sup> However, the intensity of the (020) (Fig. 3b) and (220) peaks of TiN (Fig. 3c) and their full width at the half maximum (FWHM) increased significantly with the increasing nitridation time as indicated by the dashed lines, due to the incorporation of N into the  $\text{TiO}_2$  lattice structure resulting in the formation of crystal defects. The estimated FWHM of  $\text{TiON}_6\text{NTs}$  ( $0.142^\circ$ ) is larger than that of  $\text{TiON}_4\text{NTs}$  ( $0.139^\circ$ ),  $\text{TiON}_2\text{NTs}$

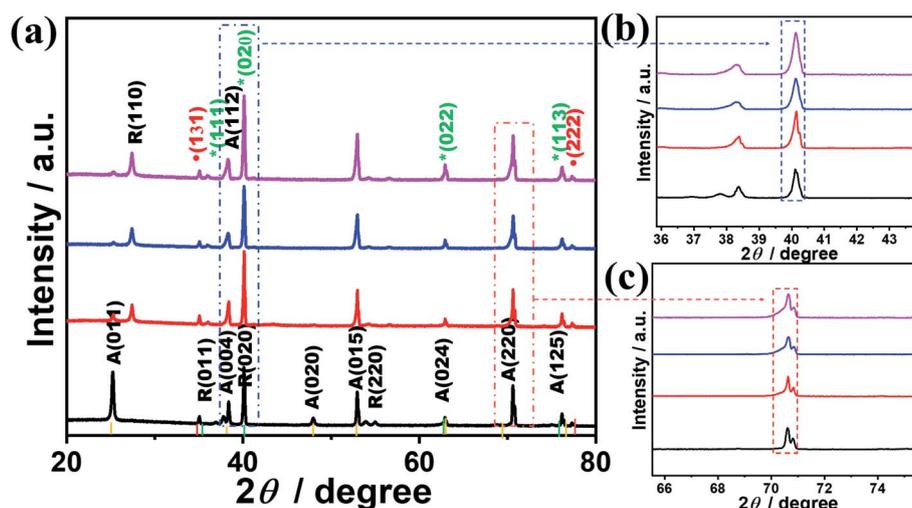


Fig. 3 (a) XRD analysis of  $\text{TiO}_2\text{NTs}$  and  $\text{TiON}_x\text{NTs}$ , (b) magnification of the (020) peak and (c) magnification of A (220). The yellow line represents  $\text{TiO}_2$  anatase (ICSD: 172914), green line represents TiN (ICSD: 236801), and the red line represents TiON (ICSD: 426340).



( $0.135^\circ$ ) and  $\text{TiO}_2\text{NTs}$  ( $0.13^\circ$ ) from (022) peak. That is also obvious in the increment of the lattice parameters of  $\text{TiON}_6\text{NTs}$  (4.245 Å),  $\text{TiON}_4\text{NTs}$  (4.223 Å), and  $\text{TiON}_2\text{NTs}$  (4.173 Å) relative to  $\text{TiO}_2\text{NTs}$  (4.112 Å), implying the expansion of the crystal lattice with the increased N content, in agreement with previous reports.<sup>45</sup>

The average crystallite size of  $\text{TiON}_6\text{NTs}$  (12.1 nm) is larger than that of  $\text{TiON}_4\text{NTs}$  (10.5 nm),  $\text{TiON}_2\text{NTs}$  (9.1 nm), and  $\text{TiO}_2\text{NTs}$  (7.2 nm) as determined from the half-peak width of the XRD peak by applying the Scherrer equation ( $L = 0.89\lambda/\beta \cos \theta$ ). The increment of the crystallite size is due to the increase of the annealing time as reported elsewhere.<sup>43,46</sup>

The valence states, surface composition, and defect-states of the typically fabricated samples were investigated by XPS analysis (Fig. 4). The binding energies of Ti, O, and N and the N-content of the as-synthesized materials are given in (Table S1†). The XPS of  $\text{TiO}_2\text{NTs}$  revealed the Ti 2p and O 1s core-level, while the ammonia-annealed  $\text{TiON}_x\text{NTs}$  showed the core-level of Ti 2p, O 1s, and N 1s (Fig. 4a). The intensity of the N 1s peak increased with increasing the nitridation time as indicated by the dashed square and the inset in Fig. 4a. The high-resolution Ti 2p spectra of  $\text{TiO}_2\text{NTs}$  revealed only two peaks assigned to Ti 2p<sub>3/2</sub> (458.4 eV) and Ti 2p<sub>1/2</sub> (464.3 eV) representing a Ti<sup>4+</sup> oxidation state (Fig. 4b). The high-resolution XPS spectra of Ti 2P in the ammonia-annealed NTs exhibited additional peaks of TiN (455.5 and 461.3 eV) assigned to the Ti<sup>3+</sup> defect sites, and TiON peaks (457.2 and 462.7 eV) attributed to the Ti<sup>2+</sup> defect sites, and a small shoulder for  $\text{TiO}_2$  (Ti2p<sub>3/2</sub> at 458.4 and Ti2p<sub>1/2</sub> at 464.3 eV) (Fig. 4b and Table S1†), indicating that Ti<sup>3+</sup> and Ti<sup>2+</sup> are the main phases in  $\text{TiON}_x\text{NTs}$  samples. The intensities of Ti<sup>3+</sup> and Ti<sup>2+</sup> defect sites peaks of TiON samples were significantly higher as compared with Ti<sup>4+</sup>, lower than those of TiN and TiON, and most of the oxide was transformed into oxynitride after ammonia-annealing. Also, the defects of Ti<sup>3+</sup> were greater as compared with both Ti<sup>2+</sup> and Ti<sup>4+</sup>, as indicated by its FWHM. Interestingly, the FWHM of TiN and

TiON peaks in  $\text{TiON}_x\text{NTs}$  increased significantly with increasing the nitridation times, implying the increase in Ti<sup>3+</sup> and Ti<sup>2+</sup> defect sites as indicated by the dashed lines in (Fig. 4b). This was attributed to the insertion of N atoms into the lattice structure of  $\text{TiO}_2$ , resulting in the replacement of oxygen atoms or the formation of the nitride and oxynitride phase, as was shown by the red-shift in the Ti 2p spectra of ammonia-annealed  $\text{TiON}_x\text{NTs}$  at longer nitridation times. This was due to the N-dopant with less electronegativity being introduced into the crystal lattice of  $\text{TiO}_2$ , resulting in the increase in the electron cloud density around Ti and converting Ti<sup>4+</sup> into Ti<sup>3+</sup> and Ti<sup>2+</sup> (Fig. 4b). The O 1s spectra in air-annealed  $\text{TiO}_2\text{NTs}$  showed three peaks ascribed to the lattice oxygen (Ti–O) at 530.2 eV, the oxygen in the adsorbed hydroxyl (Ti–OH) at 532.1 eV, and O<sub>ads</sub> at 532.4 eV. The ammonia-annealed  $\text{TiON}_x\text{NTs}$  revealed TiO, O–N, and O<sub>ads</sub> (Fig. 4c). The disappearance of the Ti–OH peak in  $\text{TiON}_x\text{NTs}$  is due to the neutralization of the oxygen vacancies in  $\text{TiO}_2$ , which decreased the concentration of Ti<sup>4+</sup> and increased the Ti<sup>3+</sup> and Ti<sup>2+</sup> defects at a high nitridation rate. This is seen in the lower stoichiometry of ammonia-annealed samples  $\text{TiON}_2\text{NTs}$  (1.5),  $\text{TiON}_4\text{NTs}$  (1.42), and  $\text{TiON}_6\text{NTs}$  (1.4) as compared to the air-annealed  $\text{TiO}_2\text{NTs}$  (1.8).

The N 1s spectra of  $\text{TiON}_x\text{NTs}$  showed mainly doublet peaks attributed to TiN at 397.3 eV and TiON at 399.0 eV, along with small shoulders around 399 eV, attributed to  $\gamma\text{-N}$ , indicating the chemisorption of N<sub>2</sub>, and at 402.0 eV corresponding to  $\beta\text{-N}$  states state, indicating the atomic N-doping in the form of the oxynitride TiON shoulder (Fig. 4d and Table S1†). Notably, increasing the annealing time resulted in a significant enhancement in the intensity and FWHM of TiON and TiN peaks, indicating the higher N content. Thus, annealing under ammonia led to the substitution of some O-sites by N, in line with previous reports on N-doped  $\text{TiO}_2$ ,<sup>28,33,42</sup> as shown by the increase in the N content with increasing the nitridation rate. The estimated amounts of N were about 1.9, 3.1, and 4.5% in

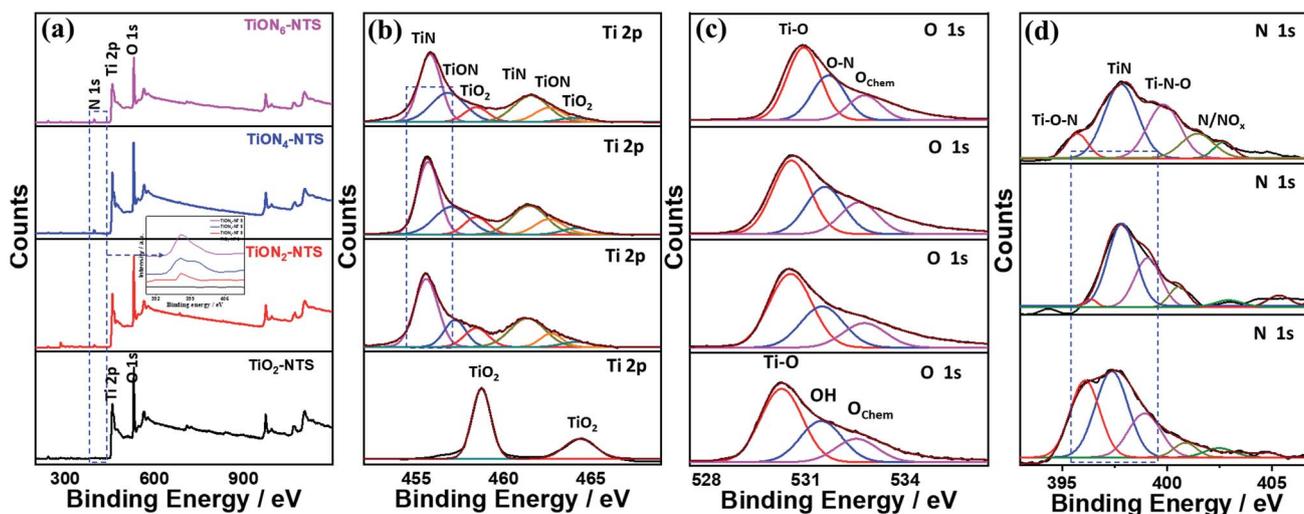


Fig. 4 (a) XPS surveys of the as-synthesized materials and their high-resolution XPS spectra of (b) Ti 2p, (c) O 1s, (d) N 1s of  $\text{TiO}_2\text{NTs}$  and  $\text{TiON}_x\text{NTs}$  before etching.



TiO<sub>2</sub>NTs, TiO<sub>4</sub>NTs, and TiO<sub>6</sub>NTs, respectively, in line with the EDX. To gain further insight into the electronic structure and valence states of the formed materials, XPS was conducted after etching 4 times (Fig. S1 and Table S1†). The XPS surveys showed the same peaks as before etching, including the Ti 2p and O 1s core-level in TiO<sub>2</sub>NTs, and Ti 2p, O 1s, and N 1s in TiO<sub>x</sub>NTs (Fig. S1a†). The high-resolution Ti 2p spectra of TiO<sub>2</sub>NTs revealed two peaks assigned to Ti 2p<sub>3/2</sub> and Ti 2p<sub>1/2</sub>, representing a Ti<sup>4+</sup> oxidation state (Fig. S1b†). Interestingly, the high-resolution XPS spectra of Ti 2P in TiO<sub>x</sub>NTs displayed TiN assigned to Ti<sup>3+</sup> defect sites and TiON attributed to Ti<sup>2+</sup> defect sites, and a small shoulder for TiO<sub>2</sub> (Fig. S1b and Table S1†). The TiN and TiON still existed after etching, contributing to the presence of Ti<sup>3+</sup> and Ti<sup>2+</sup> defect sites in the bulk, which is important for proving the various active sites, trapping sites, and delaying the electron-hole recombination during water oxidation. The spectra after etching became wider with lower intensities than before etching, which is plausible due to the lower N-content in the bulk. However, the intensity of Ti<sup>3+</sup> and Ti<sup>2+</sup> defect sites of TiO<sub>x</sub>NTs samples remained significantly higher than that of Ti<sup>4+</sup>. This is seen in the red-shifted Ti 2p spectra in the ammonia-annealed TiO<sub>x</sub>NTs at higher nitridation times. The O 1s spectra in air-annealed TiO<sub>2</sub>NTs showed Ti-O and O<sub>ads</sub>, while ammonia-annealed TiO<sub>x</sub>NTs revealed TiO, O-N, and O<sub>ads</sub> (Fig. S1c†). The N 1s spectra of TiO<sub>x</sub>NTs displayed TiN and TiON and adsorbed γ-N (Fig. S1d†). The estimated amount of N was about 1.1, and 1.9, and 2.6% in TiO<sub>2</sub>NTs, TiO<sub>4</sub>NTs, and TiO<sub>6</sub>NTs, respectively, which indicated the homogenous distribution of N in the bulk and surface.

The XPS mapping was used to further investigate the composition of the obtained materials (Fig. 5a-d). The results indicate the good distribution of Ti and O in the air-annealed TiO<sub>2</sub>NTs (Fig. 5a), while Ti, O, and N were homogeneously distributed in ammonia-annealed TiO<sub>x</sub>NTs (Fig. 5b-d). The N content in TiO<sub>x</sub>NTs increased with increasing the annealing time, as shown by the increasing number of red dots in (Fig. 5b-d). These imply the significant effect of ammonia-annealing on the creation of various Ti<sup>3+</sup> and Ti<sup>2+</sup> defects. That is also seen in the Auger electron spectroscopy recorded using a 3 kV electron beam with a current of 300 nA (Fig. 5e-g). Fig. 5e shows the AES spectra of TiLMM for air annealed TiO<sub>2</sub>NTs and TiO<sub>x</sub>NTs, which all displayed the presence of doublet peaks assigned to TiL<sub>3</sub>M<sub>2,3</sub>M<sub>4,5</sub> at (413 and 418 eV).<sup>47,48</sup> The intensity of TiL<sub>3</sub>M<sub>2,3</sub>M<sub>4,5</sub> in the TiO<sub>x</sub>NTs increased with increasing the annealing time under ammonia, which was plausibly attributed to the increasing Ti<sup>3+</sup> and Ti<sup>2+</sup> defect sites resulting from the integration of N atoms. This is seen in the appearance of a small shoulder at 397 eV, assigned to TiN in the TiO<sub>x</sub>NTs.<sup>49,50</sup> The intensity of the TiN peak increased slightly with increasing the nitridation time as shown in the inset in Fig. 5e. The difference in the intensities of the TiN peak is not high because the N contents in the ammonia-annealed TiO<sub>x</sub>NTs are too close. The OKLL spectra revealed OKL<sub>1</sub>L<sub>2,3</sub>(<sup>1</sup>p) and OKL<sub>2,3</sub>L<sub>2,3</sub> with a kinetic value of 492 eV and 511 eV, respectively (Fig. 5f). Additionally, two small humps were seen at 479 and 501 eV, assigned to OKL<sub>1</sub>L<sub>1</sub> and OKL<sub>1</sub>L<sub>2,3</sub>(<sup>3</sup>p), respectively, due to the replacement of O with N to form the Ti-ON bond and Ti-Nbond.<sup>51-53</sup> This is seen in the resolution of the N KVV spectra, including N KL<sub>1</sub>L<sub>1</sub>, KL<sub>1</sub>L<sub>2,3</sub>, and KL<sub>2,3</sub>L<sub>2,3</sub> at 352, 362, and 384 eV, respectively in the TiO<sub>x</sub>NTs, and the intensity of N KVV

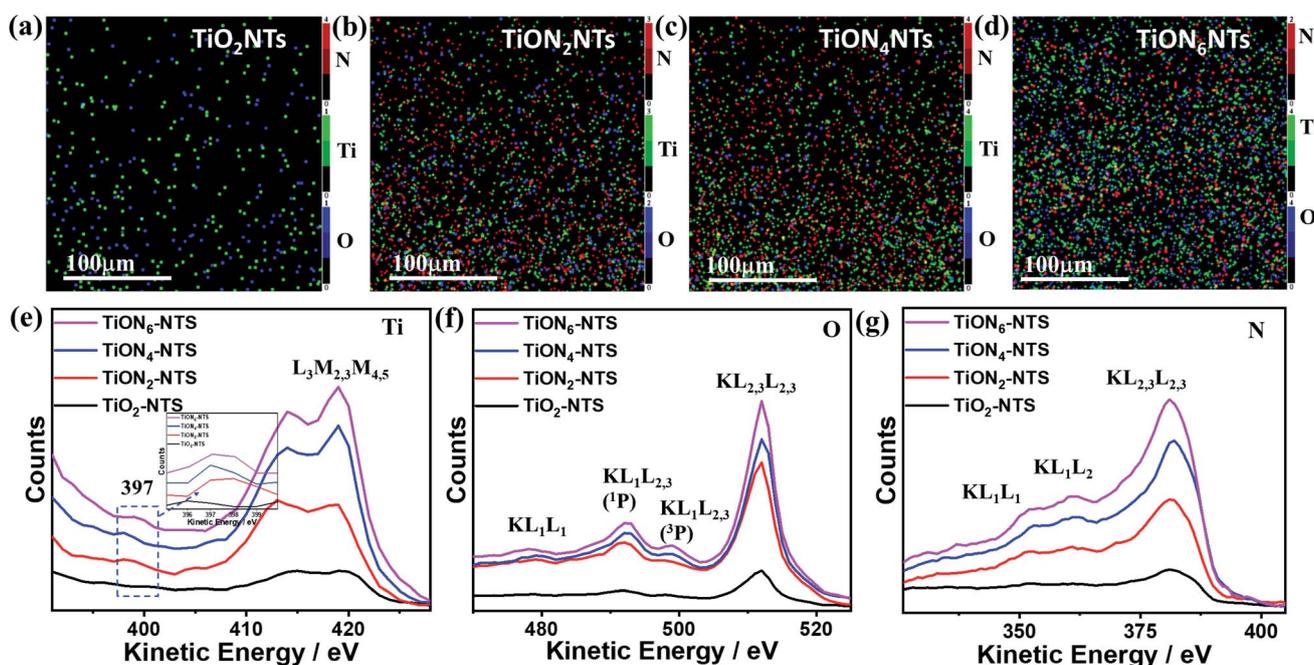


Fig. 5 XPS elemental mapping analysis for (a) TiO<sub>2</sub>NTs, (b) TiO<sub>2</sub>NTs, (c) TiO<sub>4</sub>NTs, and (d) TiO<sub>6</sub>NTs. The green, blue, and red dots represent Ti, O, and N, respectively. Auger electron spectra (AES) of (e) Ti LMM, (f) O KLL, (g) N KLL.



increased with increasing the nitridation time (Fig. 5g) resulting from the incorporation of N into the  $\text{TiO}_2$  lattice to form  $\text{Ti}^{3+}$  TiN, and  $\text{Ti}^{2+}$  TiON defect sites.<sup>28,54,55</sup> Notably, the nitridation for 2, 4, and 6 h are the optimum periods to allow N-doping without affecting the nanotube shape. This is because the nanotubes showed significant debris and distortion when the nitridation time increased to 8 h.

Fig. 6a exhibits the UV-Vis absorption spectra of typically synthesized air-annealed and ammonia-annealed  $\text{TiON}_x\text{NTs}$ . The air-annealed  $\text{TiO}_2\text{NTs}$  showed an absorption wavelength of around 410 nm. The ammonia-annealed NTs revealed a substantial blue shift in the absorption wavelength from 590 to 520 nm in the visible region. Intriguingly enough, the positive shift in the absorption wavelengths increased remarkably at a high nitridation rate. This is due to the substitution of some oxygen sites by nitrogen, enhancing the visible light absorption efficiency of ammonia-annealed NTs as compared to  $\text{TiO}_2\text{NTs}$ . This was further observed in the lower bandgap energy of ammonia-annealed NTs as compared with  $\text{TiO}_2\text{NTs}$ . Regarding this, the bandgap energy of  $\text{TiO}_2\text{NTs}$  (3.1 eV) was substantially greater than that of  $\text{TiON}_2\text{NTs}$  (2.8 eV),  $\text{TiON}_4\text{NTs}$  (2.6 eV), and  $\text{TiON}_6\text{NTs}$  (2.4 eV) as calculated using Tauc plots (Fig. S2†).

The incident photon to current conversion (IPCE) was measured in a two-electrode cell using air-annealed and ammonia-annealed NTs as working electrodes and a platinum wire as a counter electrode in 0.1 M KOH solution. The IPCE was calculated using the following equation:

$$\text{IPCE} = [1240 \times j_{\text{ph}}/\lambda \times I] \times 100$$

where  $j_{\text{ph}}$  is the photocurrent density under illumination at a wavelength  $\lambda$ , and  $I$  is the light intensity. Fig. 6b demonstrates the IPCE percentage for the as-made NTs as a function of the irradiation wavelengths. The photocurrent responses of ammonia-annealed  $\text{TiON}_x\text{NTs}$  were significantly higher as compared to air-annealed  $\text{TiO}_2\text{NTs}$  (Fig. 6b). The responses increased at a high N-content, agreeing with the UV-vis absorption results. Indeed, the  $\text{TiON}_2\text{NTs}$ ,  $\text{TiON}_4\text{NTs}$ ,  $\text{TiON}_6\text{NTs}$ , and  $\text{TiO}_2\text{NTs}$  achieved IPCEs of 12.18, 20.72, 34.74, and 4.08% at 508, 509, 520, and 488 nm, respectively (Fig. 6b). The ammonia-annealed NTs exhibited a greater IPCE efficiency at earlier wavelengths than that of  $\text{TiO}_2\text{NTs}$ , indicating the quick

response kinetics and quick charge transfer (Fig. 6c). This indicates the substantial effect of nitridation on enhancing the IPCE efficiency and retarding the electron-hole recombination. The slight drop in the IPCE efficiency at 489 nm on ammonia-annealed  $\text{TiON}_x\text{NTs}$ , owing to their inbuilt defects, implies that the photocurrents originated from the bandgap transition. The obtained IPCE of our newly developed multipodal  $\text{TiON}_6\text{NTs}$  (80 nm) (34.74) under no applied bias was higher as compared to the previously reported long nanotube (1.3  $\mu\text{m}$ )  $\text{TiON}$ -NTs (31%) and N-free (1.3  $\mu\text{m}$ )  $\text{TiO}_2\text{NTs}$  (5.3%) measured at 0.7 V in KOH,<sup>42</sup> as well as hydrogen-annealed  $\text{TiO}_2\text{NTs}$  ( $70 \pm 10$  nm) (30%)<sup>56</sup> and oxygen-annealed  $\text{TiO}_2\text{NTs}$  ( $70 \pm 10$  nm) ( $\sim 13\%$ ) in KOH,<sup>56</sup> sub-100 nm compacted  $\text{TiO}_2\text{NTs}$  (15%) under no bias in KOH,<sup>43</sup> and  $\text{TiO}_2/\text{N}$ -doped  $\text{TiO}_2$  compacted (850 nm nanotubes) (15%).<sup>33</sup> That is plausibly attributed to the multipodal nanotube shape and high defect concentration of  $\text{TiON}_6\text{NTs}$ . The photocatalytic water splitting performances of ammonia-annealed NTs were investigated relative to air-annealed  $\text{TiO}_2\text{NTs}$ . The linear sweep voltammograms (LSVs) were measured in 0.1 M KOH at  $10 \text{ mV s}^{-1}$  under light irradiation at room temperature.

The ammonia-annealed NTs were significantly superior to air-annealed  $\text{TiO}_2\text{NTs}$ . In particular, at 1.99  $V_{\text{RHE}}$ ,  $\text{TiO}_2\text{NTs}$  produced a photocurrent of  $0.57 \text{ mA cm}^{-2}$ , whereas the ammonia-annealed  $\text{TiON}_x\text{NTs}$  revealed photocurrents ranging from 1.75 to  $4.5 \text{ mA cm}^{-2}$ , implying the significant effect of N-doping on the enhancement of the photocatalytic activity (Fig. 7a). It is noteworthy that ammonia-annealed NTs showed a superior activity at earlier potentials than that of  $\text{TiO}_2\text{NT}$ . Moreover, the ammonia-annealed NTs produced greater photocurrents than  $\text{TiO}_2\text{NTs}$  under applied potential (Fig. 7b). The measured onset potential ( $E_{\text{onset}}$ ) on  $\text{TiON}_2\text{NTs}$  (1.45 V),  $\text{TiON}_4\text{NTs}$  (1.4 V), and  $\text{TiON}_6\text{NTs}$  (1.2 V) were significantly more negative than that of  $\text{TiO}_2\text{NTs}$  (1.52 V) (Fig. 7c). This plausibly emanated from the substitution of some O sites by N, which led to introducing a high concentration of vacancy-type defects inside the lattice structure of  $\text{TiO}_2\text{NTs}$ . These defects provide various electron scavenger sites facilitating the water oxidation kinetics at lower potentials, as further confirmed in the lower Tafel slope of ammonia-annealed NTs ( $0.44\text{--}0.55 \text{ V dec}^{-1}$ ) relative to  $\text{TiO}_2\text{NTs}$  ( $0.8 \text{ V dec}^{-1}$ ) (Fig. 7d).

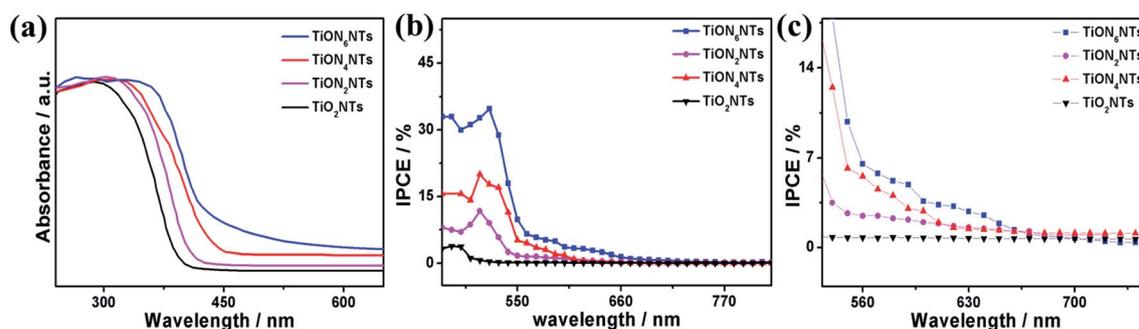


Fig. 6 (a) UV-vis transmittance, (b) IPCE spectra of the as-formed material measured in 0.1 M KOH under no applied bias and (c) zooming in on the area between 550 and 750 nm.



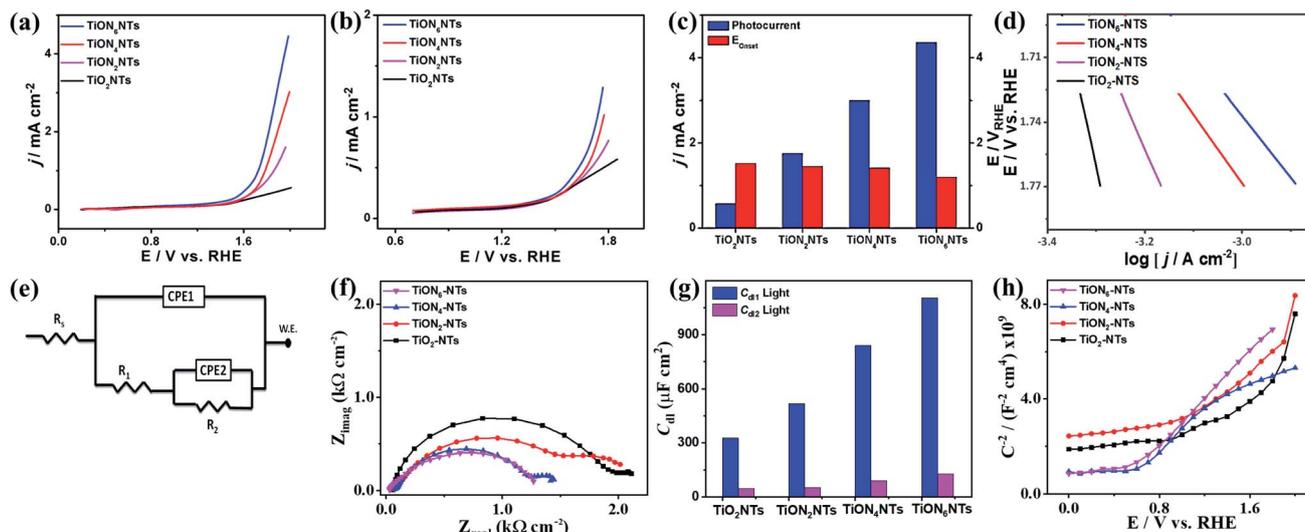


Fig. 7 (a and b) LSV of water oxidation on different catalysts measured in an aqueous solution of 0.1 M KOH at a scan rate of  $10 \text{ mV s}^{-1}$  at room temperature. (c) Comparisons of photocurrent densities and  $E_{\text{onset}}$ . (d) Tafel plot of  $\text{TiO}_2\text{NTs}$  and  $\text{TiON}_x\text{NTs}$ . (e) The utilized equivalent circuit (f) electrochemical impedance spectroscopy (EIS) Nyquist plots measured in 0.1 M KOH in a frequency range of 10 mHz to 100 kHz and a perturbation amplitude of 5 mV; (g) double layer, and (h) Mott–Schottky plots of  $\text{TiO}_2\text{NTs}$  and  $\text{TiON}_x\text{NTs}$ . All the tests were performed under light illumination.

Compared with other  $\text{TiO}_2$  or TiON nanostructures, the photocurrent obtained on our developed ammonia-annealed multipodal (80 nm)  $\text{TiON}_6\text{NTs}$  ( $4.5 \text{ mA cm}^{-2}$ ) was superior to that reported for Co–TiON nanowires (80–100 nm) ( $0.61 \text{ mA cm}^{-2}$ ),<sup>57</sup> TiON nanowires (4.4  $\mu\text{m}$ ) ( $0.23 \text{ mA cm}^{-2}$ ),<sup>58</sup> and compacted  $\text{TiO}_2\text{NTs}$  ( $70 \pm 10 \text{ nm}$ ) ( $0.45 \text{ mA cm}^{-2}$ ),<sup>43</sup> titanium nitride/titanium oxide (TiN/ $\text{TiO}_2$ ) nanocomposite ( $0.12 \text{ mA cm}^{-2}$ ),<sup>59</sup> and long TiON nanotubes (1.3  $\mu\text{m}$ ) ( $2.25 \text{ mA cm}^{-2}$ )<sup>42</sup> measured under similar conditions in KOH electrolyte under light illumination (a xenon ozone-free lamp 100 or 300 W).

Moreover, we measured the photocatalytic water splitting performances of ammonia-annealed NTs relative to ammonia-annealed  $\text{TiO}_2$  nanotubes with different lengths of 1.2  $\mu\text{m}$  (denoted  $\text{TiONNTs}$  1.2) and 500 nm (denoted  $\text{TiONNTs}$  500), as well as commercial  $\text{TiO}_2$  nanoparticles (Fig. S3<sup>†</sup>). The current densities of ammonia-annealed  $\text{TiON}_6\text{NTs}$  ( $4.5 \text{ mA cm}^{-2}$ ) were 3.19, 2.14, 11.25, and 20.4 times higher than that of  $\text{TiONNTs}$ -1.2 ( $1.41 \text{ mA cm}^{-2}$ ),  $\text{TiONNTs}$ -500 ( $2.1 \text{ mA cm}^{-2}$ ), N-free  $\text{TiO}_2\text{NTs}$ -1.2 ( $0.4 \text{ mA cm}^{-2}$ ), and  $\text{TiO}_2$  nanoparticles ( $0.225 \text{ mA cm}^{-2}$ ) (Fig. S3<sup>†</sup>). This is due to the uniformity, multipodal nanotube shape, and high defect concentration of  $\text{TiON}_6\text{NTs}$ , which plausibly enhanced the conductivity and accelerated charge mobility. It is universally accepted that sub-100 nm nanotubes have various unique merits relative to traditional compacted long nanotubes, including but not limited to greater surface area, shorter aspect ratio, and directional/quick charge transfer, as well as a short electron pathway.<sup>43</sup> This is in addition to the effective electron–hole separation and better light-harvesting ability that drive the water-splitting at a lower potential relative to traditional long nanotubes. Meanwhile, the multipodal shape provides a graded refractive index, large surface, and easier charge separation at the core–leg interface enabling greater volume ratio and higher scattering.<sup>60</sup> In contrast, the

long diameter of the compact nanotube (over 170 nm) can act as a sub-wavelength structure that scatters light in Rayleigh fashion as reported before.<sup>60</sup>

That was furthered proved by measuring the electrochemical impedance spectroscopy (EIS) under light for  $\text{TiO}_2\text{NTs}$  and  $\text{TiON}_x\text{NTs}$ . The equivalent circuit (EC) was utilized to fit and analyze the measured data (Fig. 7e). A two-time constant equivalent circuit was employed, which is primarily used for electrodes with coatings or porous oxide layers on top. The EIS parameters, such as the electrolyte resistance ( $R_s$ ), the charge transfer resistance at the oxide or the oxynitride/solution interface ( $R_1$ ), the charge transfer resistance at the metal solution interface ( $R_2$ ), the two constant phase elements (CPE1 and CPE2) associated with the resistances mentioned above, and the deviation parameters ( $n_1$  and  $n_2$ ), are listed in Table S2.<sup>†</sup> A constant phase element is used instead of a pure capacitor to express the non-ideal behavior (indicated by the depressed semicircles) of the double-layer capacitance because of the non-uniform (i) thickness of the oxide/nitrided layer, (ii) reaction kinetics on the surface, (iii) current distribution, in addition to (iv) surface roughness.<sup>61</sup> The diameters of the depressed semicircles of  $\text{TiO}_x\text{NTs}$  relative to  $\text{TiO}_2\text{NTs}$  are shown in Fig. 7f. Increasing the N-content leads to decreasing the diameter of the thus-obtained  $\text{TiO}_x\text{NTs}$ , which indicates their quick charge mobility and electrolyte–electrode conductivity relative to air-annealed  $\text{TiO}_2\text{NTs}$ . Fig. 7g depicts the double-layer capacitance ( $C_{\text{dl}}$ ) derived from the variables in Table S2<sup>†</sup> using the equation below:

$$C_{\text{dl}} = [(Y_o \times R_{\text{ct}})^{1/m}] / R_{\text{ct}} \quad (1)$$

It can be noted that the double layer capacitance is inversely proportional to the impedance values (Fig. 7g); the  $C_{\text{dl}}$  values in



TiON<sub>x</sub>NTs were higher than that in TiO<sub>2</sub>NTs, indicate the dielectric nature of the TiO<sub>2</sub>NTs substrate. This is more obvious in the decreasing  $R_1$ ,  $R_2$ ,  $R_g$ , and  $n_1$ , and  $n_2$  in TiON<sub>x</sub>NTs as compared to TiO<sub>2</sub>NTs (Table S2†).

Mott–Schottky plots were utilized to elucidate the charge distribution on the as-synthesized interface *versus* the electrolyte by measuring the electrode capacitance  $C$  as a function of electrode potential  $E$  (Fig. 7h). It is worth mentioning that all samples provided a positive slope, which is characteristic of the n-type TiO<sub>2</sub> semiconductor. Hence, the donor density ( $N_d$ ) was calculated using the equation below:

$$C^{-2} = (2/e\epsilon\epsilon_0AN_d) \times (E - E_{FB} - (K_b/T)e) \quad (2)$$

where  $C$ ,  $e$ ,  $\epsilon$ ,  $\epsilon_0$ ,  $A$ ,  $E_{FB}$ ,  $K_b$ , and  $T$  are the space charge capacitance, the electron charge, the dielectric constant, the vacuum permittivity, the tested surface area, the flat band potential, the Boltzmann constant, and the absolute temperature, respectively. Additionally,  $E_{FB}$  can be determined from the extrapolation of the linear portion to  $1/C^2 = 0$ . Generally, it can be noted that the flat band potential shifts negatively with increasing the TiON<sub>x</sub>NTs as compared with TiO<sub>2</sub>NTs (Fig. 7h). There was a considerable improvement in the electron density in the order of TiON<sub>6</sub>NTs > TiON<sub>4</sub>NTs, ( $4.15 \times 10^{18} \text{ cm}^{-3}$ ) as compared with TiON<sub>2</sub>NTs ( $3.93 \times 10^{18} \text{ cm}^{-3}$ ). This was obvious in the increase of the donor density band potentials obtained from Mott–Schottky plots for TiON<sub>x</sub>NTs as compared to TiO<sub>2</sub>NTs (Table S3†). Fig. 8 shows the energy level diagram for the typically synthesized materials. In particular, N-doping introduced the N 2p band above the O 2p valence band, resulting in the narrowing of the bandgap of TiO<sub>2</sub> from 3.2 eV to 2.4 eV.<sup>42</sup> Hence, *via* the visible-light absorption, the electrons migrate from the valence band to the conduction band, which shifts the optical absorption to the visible light region and enhances the visible light responses of TiON<sub>x</sub>NTs (Fig. 8a). The proposed photoelectrochemical water splitting mechanism on TiON<sub>6</sub>NTs is shown in (Fig. 8b).

Upon light irradiation, the electrons and holes are generated in the conduction band and the valence band, respectively. The electrons and holes are scavenged by the O<sub>2</sub> molecules to produce superoxide radical anions (O<sub>2</sub><sup>•−</sup>) and hydroxyl radicals (OH<sup>•</sup>), which are highly active and act as oxidative species facilitating water oxidation under lower potential (Fig. 8b).

The type and concentration of the defects in the air-annealed TiO<sub>2</sub>NTs and ammonia-annealed TiON<sub>x</sub>NTs were benchmarked using positron annihilation spectroscopy (PALS). The injected

positrons through TiO<sub>2</sub> are thermalized and annihilated by electrons, which lead to the emission of  $\gamma$  rays and allows the measurement of the lifetime of positrons. The positrons are distributed in the area with low electron density (*i.e.*, vacancy-type defects, vacancy clusters, and microvoids). Thus, the electron-positron annihilation photon allows the measurement of the lifetimes ( $t_1$ ,  $t_2$ , and  $t_3$ ) of positrons and their intensities ( $I_1$ ,  $I_2$ , and  $I_3$ ) as indicators of the defects. The results showed the resolved positron lifetimes, including the shorter lifetime ( $\tau_1$ ), longer positron lifetime ( $\tau_2$ ), and longest lifetime components ( $\tau_3$ ) along with their related intensities  $I_1$ ,  $I_2$ , and  $I_3$  (Table 1). The respective  $\tau_1$  values attributed to the free annihilation of positrons in the defect-free crystals of TiON<sub>2</sub>NTs (178 ps), TiON<sub>4</sub>NTs (181 ps), and TiON<sub>6</sub>NTs (188 ps) were significantly higher than that of TiO<sub>2</sub>NTs (174 ps). The increment in  $\tau_1$  is attributed to the higher content of monovacancies and/or shallow positron traps in the ammonia-annealed samples, which decreased the surrounding electron density and subsequently increased the lifetime of  $\tau_1$  in TiO<sub>x</sub>NNTs as compared to in air-annealed TiO<sub>2</sub>NTs. Therefore, the prolonged  $\tau_1$  of TiON<sub>x</sub>NTs validated that a huge number of small neutral Ti<sup>3+</sup>–N vacancy associates were introduced into the TiO<sub>2</sub> lattice by nitridation.

The lifetime  $\tau_2$  is larger than  $\tau_1$ , which implies that  $\tau_2$  originated from positrons captured by defects of larger size. Thus, the  $\tau_2$  of TiON<sub>2</sub>NTs (297 ps), TiON<sub>4</sub>NTs (301 ps), and TiON<sub>6</sub>NTs (311 ps) were greater than that of TiO<sub>2</sub>NTs (288 ps), implying the presence of larger-sized vacancy clusters attributed to the interaction among small neutral Ti<sup>3+</sup>–nitrogen-vacancy associates. The average electron density in larger-sized defects is lower than that in small-sized defects, which decreases the annihilation rate and increases the positron lifetime correspondingly. The longest lifetime ( $\tau_3$ ) is plausibly attributed to the annihilation of orthopositronium atoms formed in the large voids in semiconductors. The  $\tau_3$  of ammonia-annealed TiON<sub>2</sub>NTs (10.4 ps), TiON<sub>4</sub>NTs (12.1 ps), and TiON<sub>6</sub>NTs (13.5 ps) are higher than that of air annealed TiO<sub>2</sub>NTs (8.3 ps). This demonstrated the higher content of the few voids of N-vacancy associates on the nanoscale in ammonia-annealed samples.

In addition to the lifetimes of the positrons, their relative intensities provide information on the relative concentration of the defects. The relative intensities ( $I_1$ ) of TiON<sub>2</sub>NTs (57.4%), TiON<sub>4</sub>NTs (55.2%), and TiON<sub>6</sub>NTs (52.9%) were close to that of TiO<sub>2</sub>NTs (60.5%). The relative  $I_2$  of TiON<sub>2</sub>NTs (35.4%), TiON<sub>4</sub>NTs (36.6%), and TiON<sub>6</sub>NTs (37.9%) were slightly lower than that of TiO<sub>2</sub>NTs (34.5%). The  $I_1$  to  $I_2$  ratios of TiON<sub>2</sub>NTs (1.6), TiON<sub>4</sub>NTs (1.5), and TiON<sub>6</sub>NTs (1.39) were slightly lower than

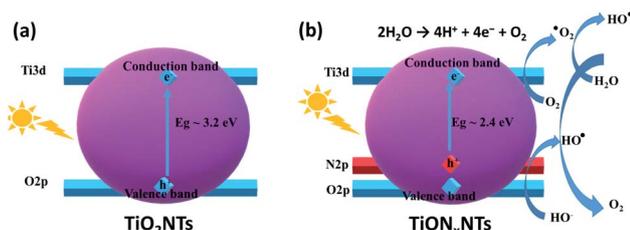


Fig. 8 Energy level diagrams for (a) TiO<sub>2</sub>NTs and (b) TiON<sub>x</sub>NTs, as well as the proposed water splitting mechanism.

Table 1 Obtained positron lifetimes ( $t_1$ ,  $t_2$ , and  $t_3$ ) and their intensities ( $I_1$ ,  $I_2$ , and  $I_3$ ) of TiO<sub>2</sub>NTs and TiON<sub>x</sub>NTs

Samples	$t_1$ (ps)	$I_1$ (%)	$t_2$ (ps)	$I_2$ (%)	$t_3$ (ps)	$I_3$ (%)
TiO <sub>2</sub> NTs	174	60.5	288	34.5	8.3	5
TiON <sub>2</sub> NTs	178	57.4	297	35.4	10.4	7.2
TiON <sub>4</sub> NTs	181	55.2	301	36.6	12.1	8.9
TiON <sub>6</sub> NTs	188	52.9	311	37.9	13.5	9.2



that of TiO<sub>2</sub>NTs (1.75). This demonstrates the decrease in the concentration of bulk defects ( $C_{bd}$ ) to surface defects ( $C_{sd}$ ) of ammonia-annealed TiON<sub>x</sub>NTs relative to air-annealed TiO<sub>2</sub>NTs in addition to a higher concentration of monovacancies than the boundary-like defect. The relative intensities  $I_3$  of TiON<sub>2</sub>NTs (7.2%), TiON<sub>4</sub>NTs (8.9%), and TiON<sub>6</sub>NTs (9.2%) were higher than that of TiO<sub>2</sub>NTs (5%). This indicates the greater concentration of the voids of N-vacancy associates on the nanoscale in ammonia-annealed TiON<sub>x</sub>NTs as compared to air-annealed. The slight drop in the  $I_3$  originated from the sharp increase in  $I_1$  and  $I_2$ . The summation of  $I_1 + I_2 + I_3$  should be equal to 100. Impressively, it is universally accepted that reducing the  $C_{bd}$  to  $C_{sd}$  led to the retardation of the electron-hole recombination.<sup>37,39</sup> As expected, the  $\tau_3$  of TiON<sub>2</sub>NTs (10.4 ps), TiON<sub>4</sub>NTs (12.1 ps), and TiON<sub>6</sub>NTs (13.5 ps) were slightly higher than that of TiO<sub>2</sub>NTs (8.3 ps), demonstrating their higher content of the few voids of vacancy associates on the nanoscale. The relative intensities  $I_3$  of ammonia-annealed TiON<sub>x</sub>NTs were lower than that of TiO<sub>2</sub>NTs.

These results indicate that annealing under ammonia gas introduced different vacancy-type defects such as monovacancies, vacancy clusters, and a few voids inside the lattice structure of TiO<sub>2</sub>NTs. Such defects led to a significant reduction in the bandgap energy, retarding the electron-hole recombination and enhancing the UV-visible light absorption and photocatalytic water splitting. This is attributed to the substantial effect of the defects/vacancies on boosting the photocurrent in n-type TiO<sub>2</sub>.<sup>34,37,41</sup> These defects form inter-bandgap states underneath the conduction band minimum and provide extra charge carriers under UV-light irradiation. Additionally, owing to the great electron trapping ability of defects, the lifetime of the photoelectrons increased significantly, resulting in supreme activity for solar-driven water splitting.

## Conclusion

Herein, we rationally synthesized ultrathin, well-aligned, and uniform sub-100 nm multipodal TiO<sub>2</sub>NTs nanotubes (80 ± 2 nm length) *via* the electrochemical anodic oxidation of Ti-foil in formamide-based electrolytes. The as-formed TiO<sub>2</sub>NTs were annealed under ammonia for 2, 4, and 6 h to form TiON<sub>2</sub>NTs, TiON<sub>4</sub>NTs, and TiON<sub>6</sub>NTs, respectively. The N-content was ~1.7, and 3.2, and 4.9%, in TiON<sub>2</sub>NTs, TiON<sub>4</sub>NTs, and TiON<sub>6</sub>NTs, respectively. The HRTEM, XPS, AES, and PALS warranted that a high concentration of vacancy-type defects was introduced inside the TiO<sub>2</sub>NTs lattice structure. The N-content and its subsequent defects inside the TiO<sub>2</sub>NTs lattice increased with the increment of the nitridation time that formed a mixture of Ti-nitride and oxynitride with various defect states. These kinds of defects decreased the bandgap energy to 2.4 eV, enhanced the visible-light response, IPCE, photocurrent density (by 8 times), and accelerated the charge carrier collection efficiency of ammonia-annealed TiON<sub>x</sub>NTs as compared to air-annealed TiO<sub>2</sub>NTs. The sub-100 nm nanotubes TiON<sub>6</sub>NTs outperformed the long compacted TiON<sub>x</sub>NTs with different lengths and TiO<sub>2</sub> nanoparticles. This

paper could pave the way towards optimizing the defect state of TiO<sub>2</sub>-based photocatalysts for solar-driven water splitting.

## Conflicts of interest

There are no conflicts of interest to declare.

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